

iJB12060A006V-*-R**

EVALUATION DATA

型式データ

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使用記号 Terminology used

定義 Definition

Vin	入力電圧	Input voltage
Vo	出力電圧	Output voltage
EN	EN端子電圧	EN pin voltage
Iin	入力電流	Input current
Io	出力電流	Output current
Ta	周囲温度	Ambient temperature

※ 当社測定条件における結果であり、参考値としてお考え願います。

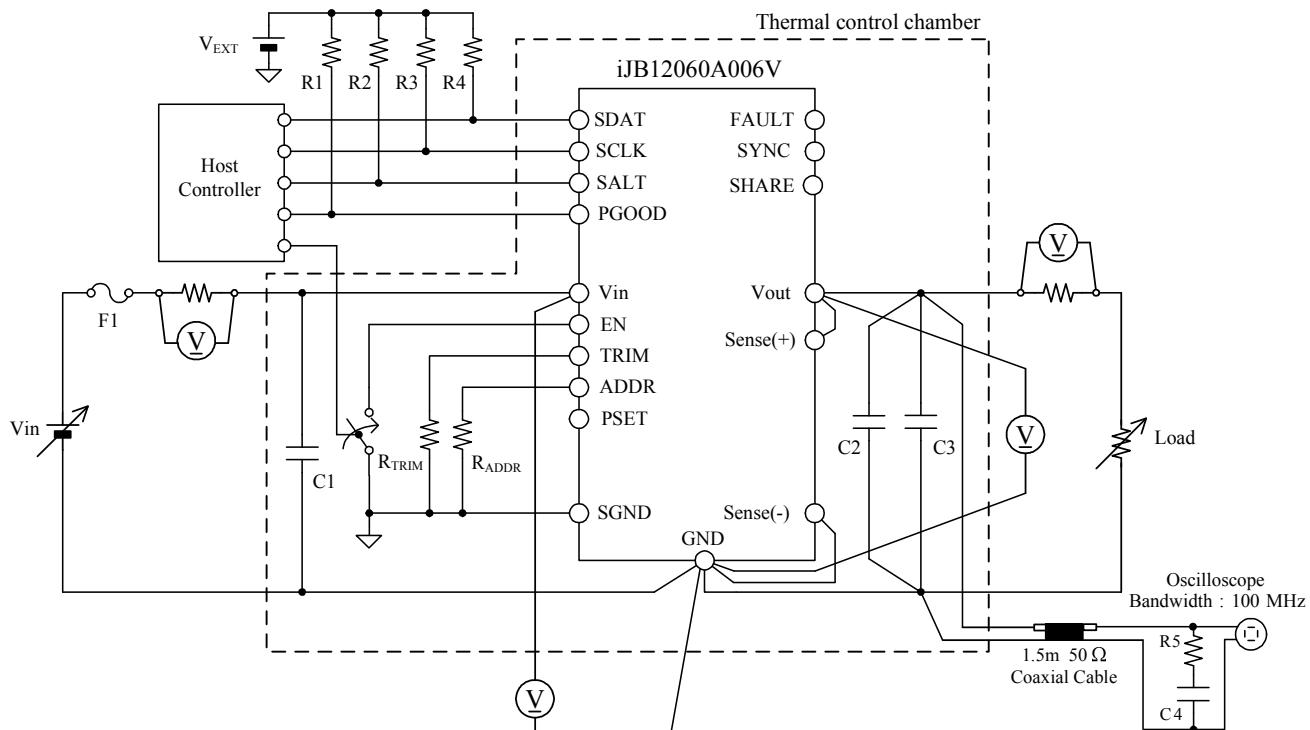
Test results are reference data based on our measurement condition.

1. 測定方法 Evaluation Method

1.1 測定回路 Measurement Circuits

測定回路1 Measurement Circuit 1

- 静特性 Steady state data
- 待機電力特性 Standby power characteristics
- 通電ドリフト特性 Warm up voltage drift characteristics
- 過電流保護特性 Over current protection (OCP) characteristics
- 出力リップルノイズ波形 Output ripple and noise waveform



C1 : 22μF Ceramic Capacitor × 6 Parallel

R1, R2, R3, R4 : 10kΩ

C2 : 100uF Ceramic Capacitor × 10 Parallel

R_{TRIM} : 52.3kΩ

C3 : 0.1uF Ceramic Capacitor

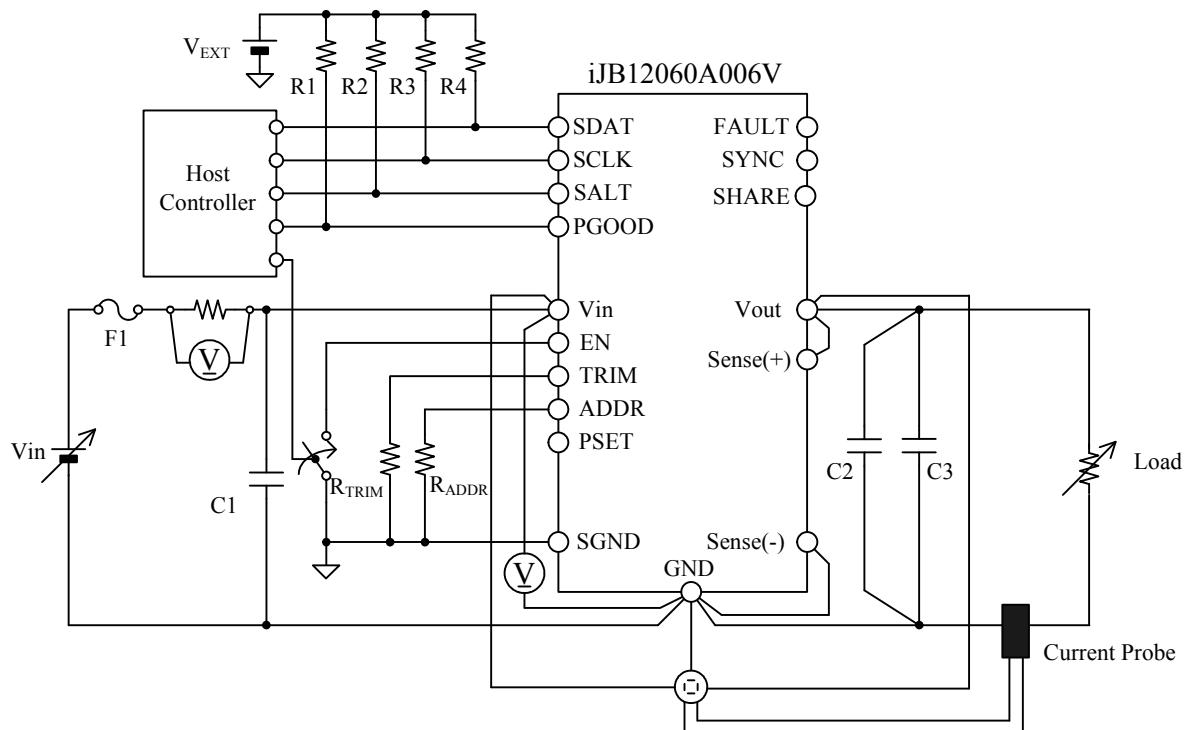
R_{ADDR} : Open

C4 : 4700pF Ceramic Capacitor

R5 : 50Ω

測定回路2 Measurement Circuit 2

- 出力立ち上がり特性 Output rise characteristics
- 出力立ち下がり特性 Output fall characteristics
- 過電圧保護特性 Over voltage protection (OVP) characteristics
- 過渡応答(負荷急変)特性 Dynamic load response characteristics

C1 : 22 μ F Ceramic Capacitor \times 6 ParallelR1, R2, R3, R4 : 10k Ω C2 : 100 μ F Ceramic Capacitor \times 10 ParallelR_{TRIM} : 52.3k Ω C3 : 0.1 μ F Ceramic CapacitorR_{ADDR} : Open

C4 : 4700pF Ceramic Capacitor

1.2 使用測定機器 List of equipment used

	EQUIPMENT USED	MANUFACTURER	MODEL NO.
1	DIGITAL STORAGE OSCILLOSCOPE	National Insturument	PXI-5112
2	DIGITAL MULTIMETER	Agilent	34901A
3	DIGITAL MULTIMETER	National Insturument	PXI-4070
4	CURRENT PROBE	Tektronix	TCP303
5	DYNAMIC DUMMY LOAD	Chroma	63303
6	DC POWER SUPPLY	Chroma	62012P-80-60
7	THERMAL CONTROL	Thermonics	T-2500E
8	DIGITAL STORAGE OSCILLOSCOPE	YOKOGAWA ELECT.	DLM2054
9	DIGITAL STORAGE OSCILLOSCOPE	Lecroy	DS-4354M
10	CARBON PLATE RHEOSTATS	YAMABISHI ELECTRIC	RC-3
11	SHUNT RESISTER	YOKOGAWA ELECT.	2215

2. 特性データ Characteristics

2.1 静特性 Steady state data

(1) 入力変動、負荷変動、温度変動 Line regulation, Load regulation, Temperature drift

Vo= 0.6 V

1. Line regulation and Load regulation

Condition Ta : 25°C

Io \ Vin	8VDC	12VDC	14VDC	Line regulation	
0%	0.5995V	0.5990V	0.5989V	0.6mV	0.1%
50%	0.6004V	0.6000V	0.6002V	0.4mV	0.1%
100%	0.6002V	0.6001V	0.6000V	0.2mV	0.0%
Load regulation	0.9mV	1.1mV	1.3mV		
	0.2%	0.2%	0.2%		

2. Temperature drift

Conditions Vin : 12VDC
Io : 100%

Ta	-40°C	+25°C	+85°C	Temperature stability	
Vo	0.6004V	0.6001V	0.5993V	1.1mV	0.2%

Vo= 1.0 V

1. Line regulation and Load regulation

Condition Ta : 25°C

Io \ Vin	8VDC	12VDC	14VDC	Line regulation	
0%	0.9997V	0.9986V	0.9979V	1.8mV	0.2%
50%	1.0009V	0.9991V	0.9987V	2.2mV	0.2%
100%	1.0019V	0.9994V	0.9988V	3.1mV	0.3%
Load regulation	2.2mV	0.8mV	0.9mV		
	0.2%	0.1%	0.1%		

2. Temperature drift

Conditions Vin : 12VDC
Io : 100%

Ta	-40°C	+25°C	+85°C	Temperature stability	
Vo	0.9990V	0.9994V	0.9983V	1.1mV	0.1%

Vo= 2.0 V

1. Line regulation and Load regulation

Condition Ta : 25°C

Io \ Vin	10VDC	12VDC	14VDC	Line regulation	
0%	2.0050V	2.0046V	2.0018V	3.2mV	0.2%
50%	2.0075V	2.0073V	2.0045V	3.0mV	0.2%
100%	2.0077V	2.0076V	2.0060V	1.7mV	0.1%
Load regulation	2.7mV	3.0mV	4.2mV		
	0.1%	0.2%	0.2%		

2. Temperature drift

Conditions Vin : 12VDC
Io : 100%

Ta	-40°C	+25°C	+85°C	Temperature stability	
Vo	2.0065V	2.0076V	2.0049V	2.7mV	0.1%

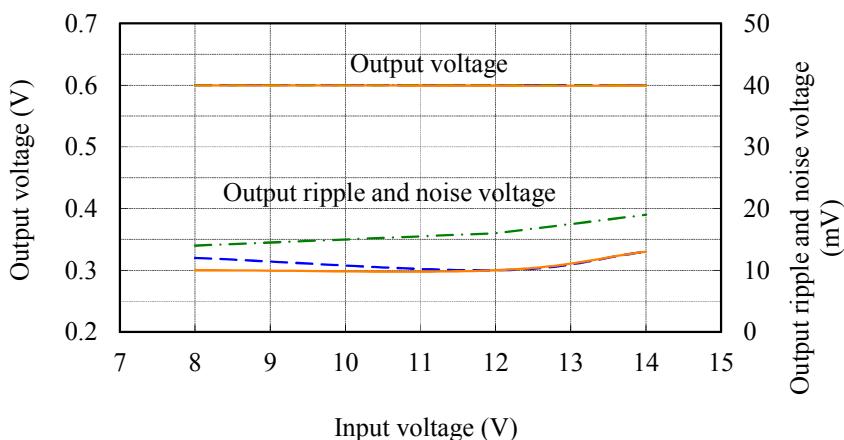
(2) 出力電圧、出力リップル・ノイズ電圧 対 入力電圧

Output voltage and Output ripple and noise voltage vs. Input voltage

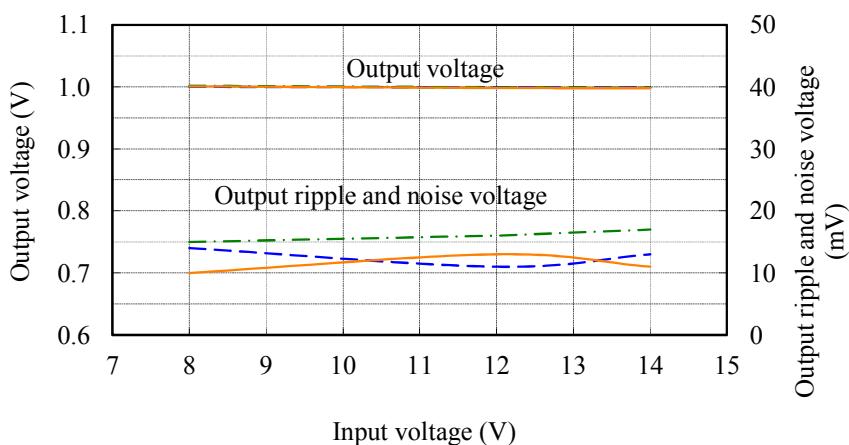
Transient Response : Standard Option

Conditions Io : 100 %
 Ta : -40 °C —
 : 25 °C —
 : 85 °C —

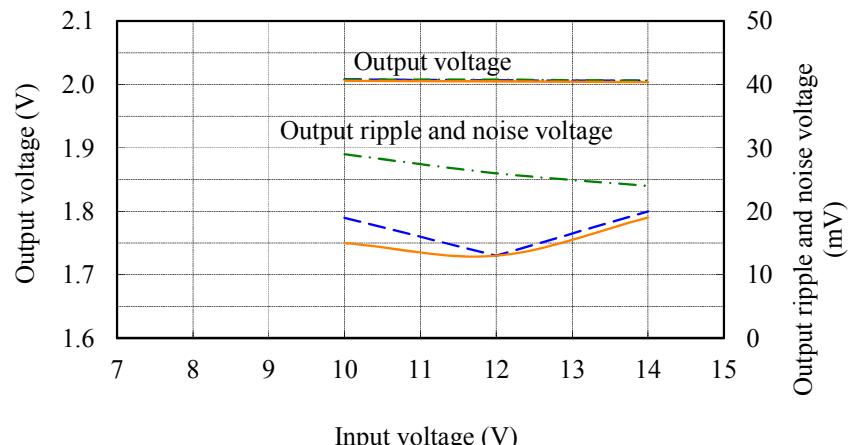
Vo= 0.6 V



Vo= 1.0 V



Vo= 2.0 V



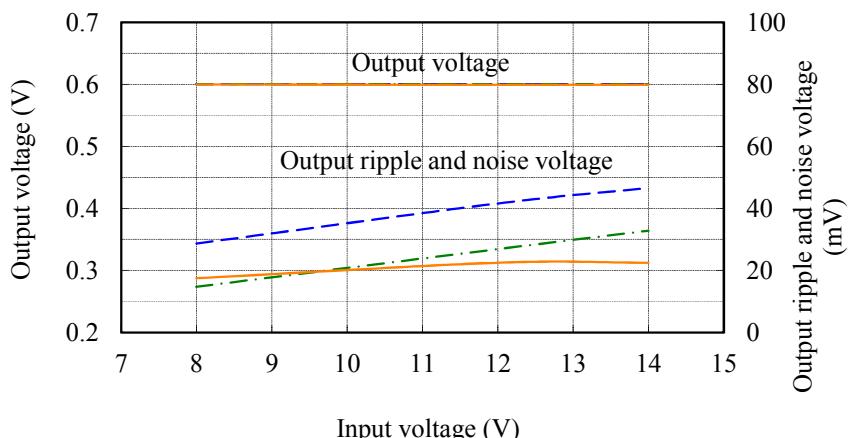
(2) 出力電圧、出力リップル・ノイズ電圧 対 入力電圧

Output voltage and Output ripple and noise voltage vs. Input voltage

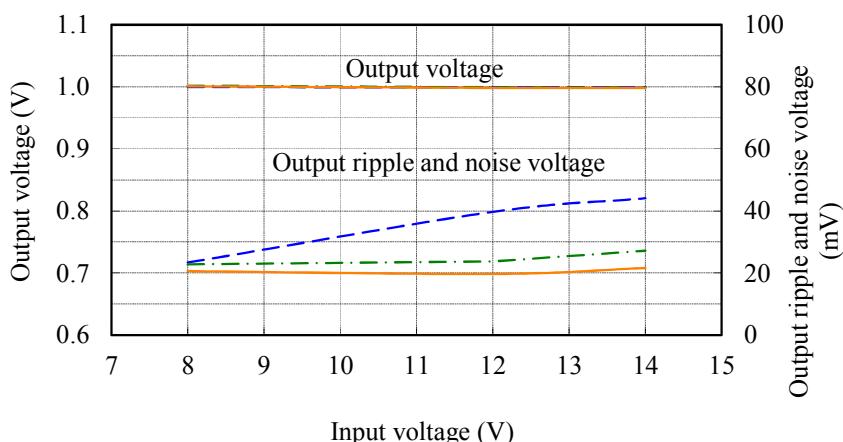
Transient Response : Enhanced Option

Conditions	Io	:	100 %
	Ta	:	-40 °C
		:	25 °C
		:	85 °C

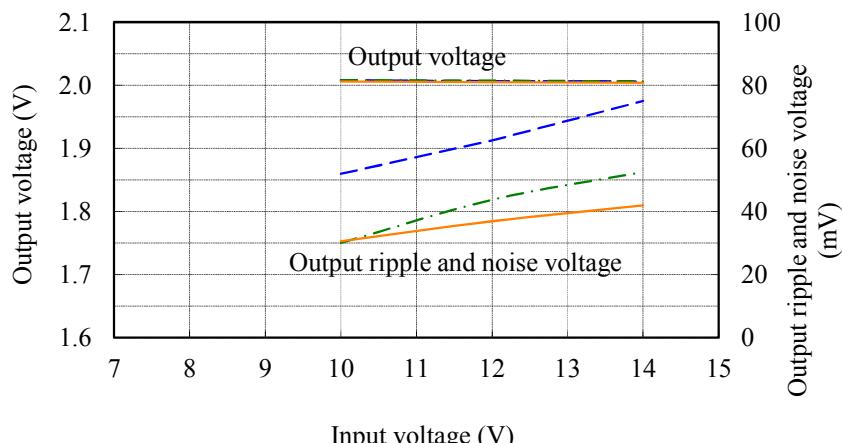
Vo= 0.6 V



Vo= 1.0 V

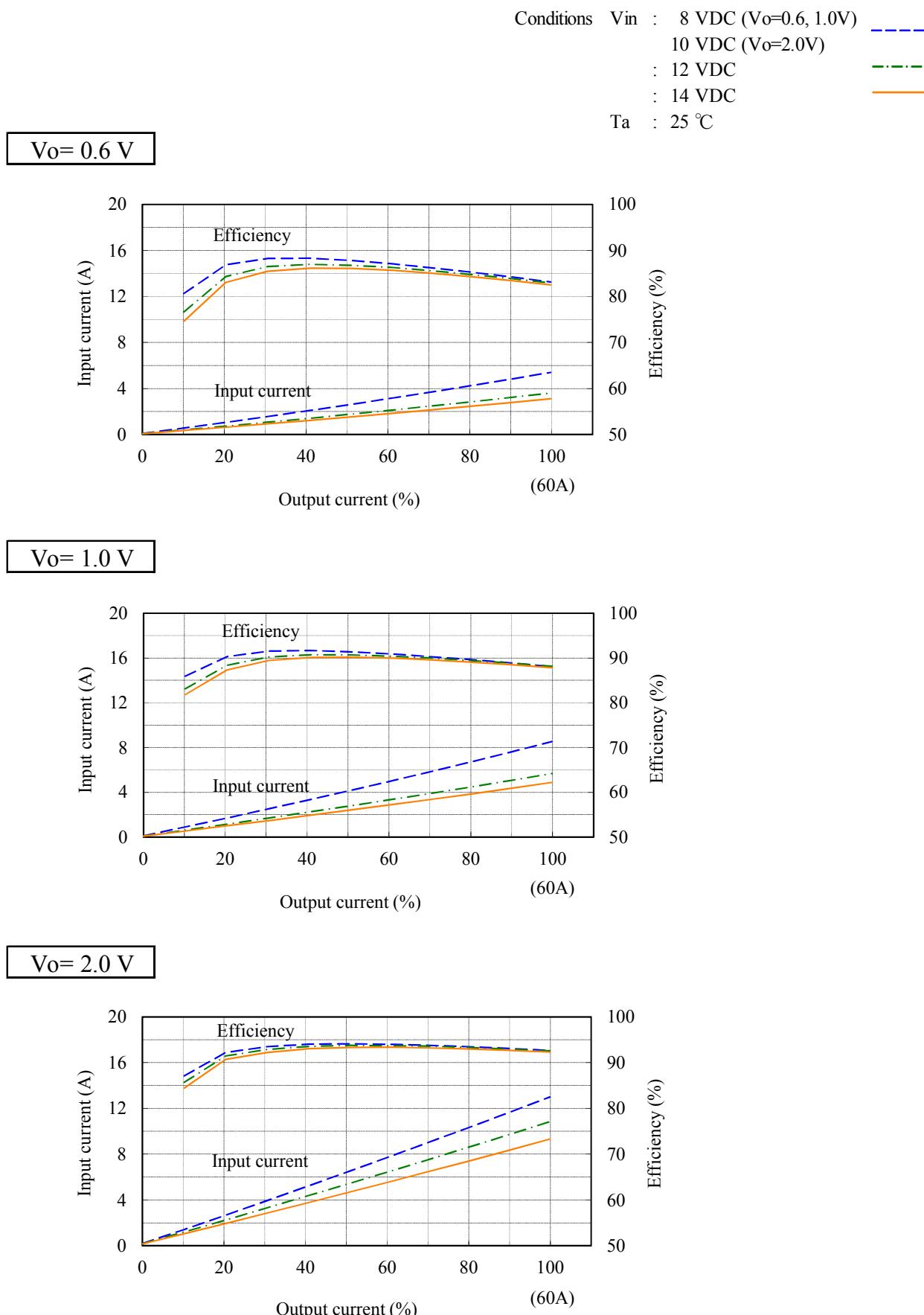


Vo= 2.0 V

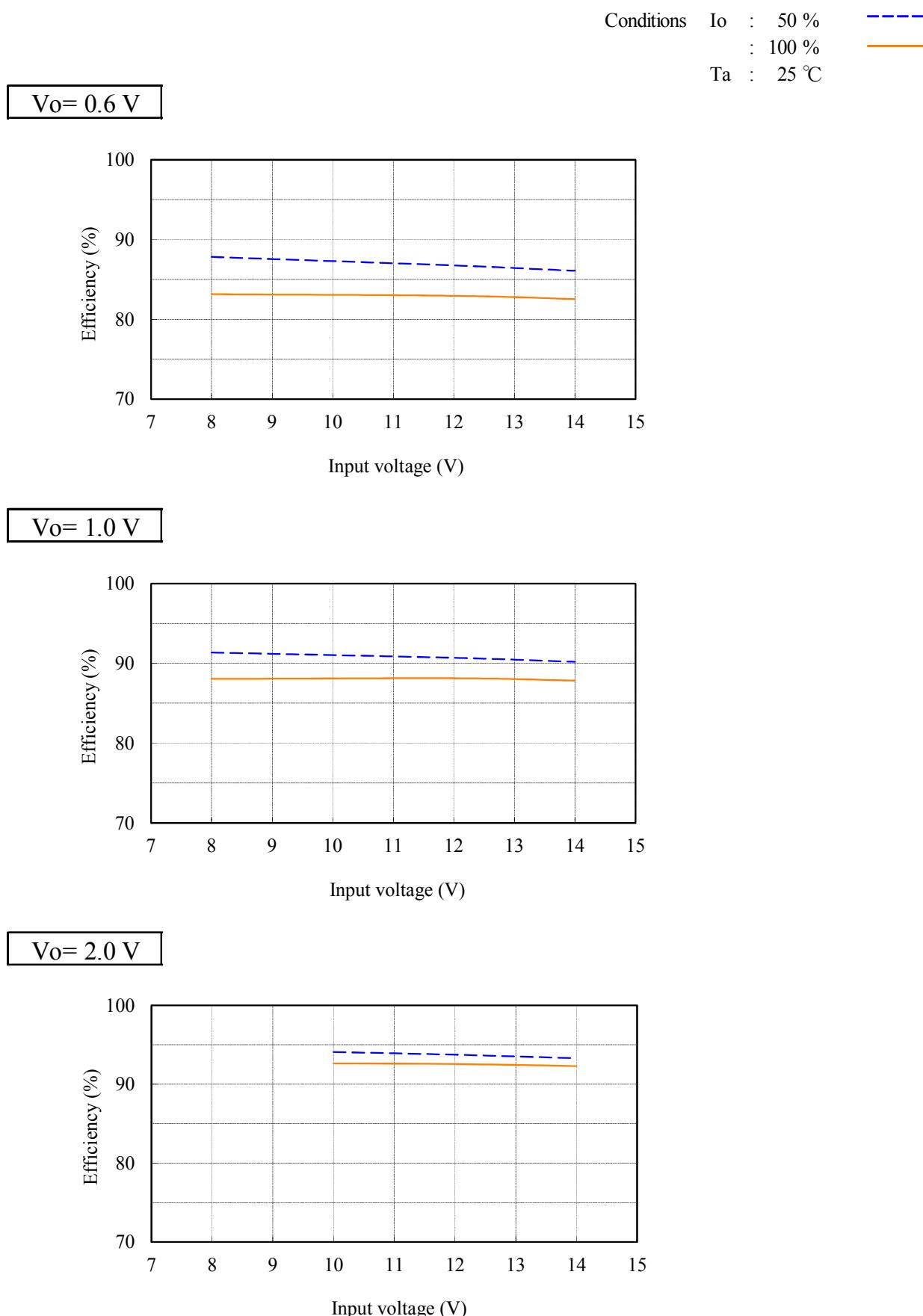


(3) 入力電流、効率 対 出力電流

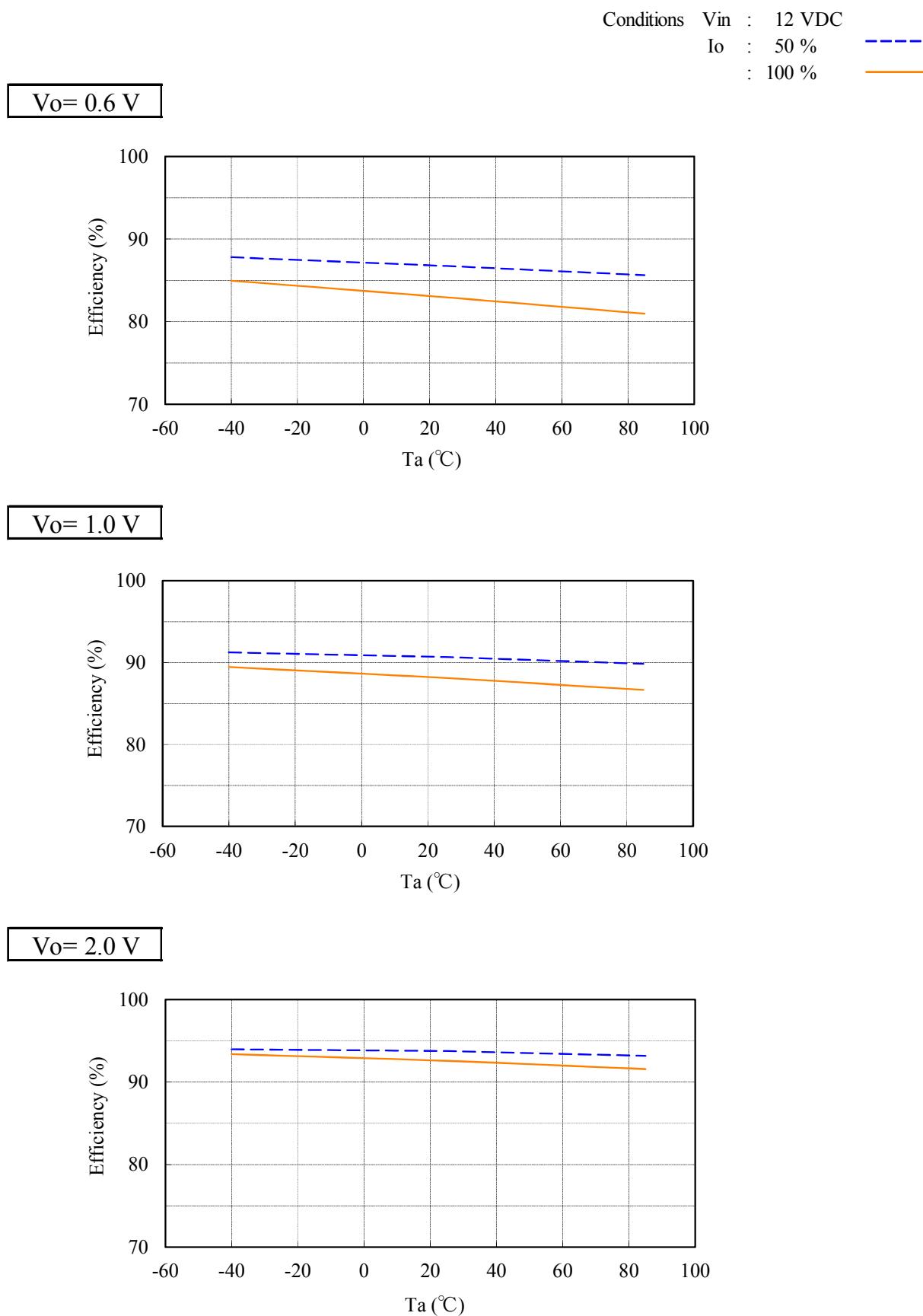
Input current and Efficiency vs. Output current



(4) 効率 対 入力電圧 Efficiency vs. Input voltage

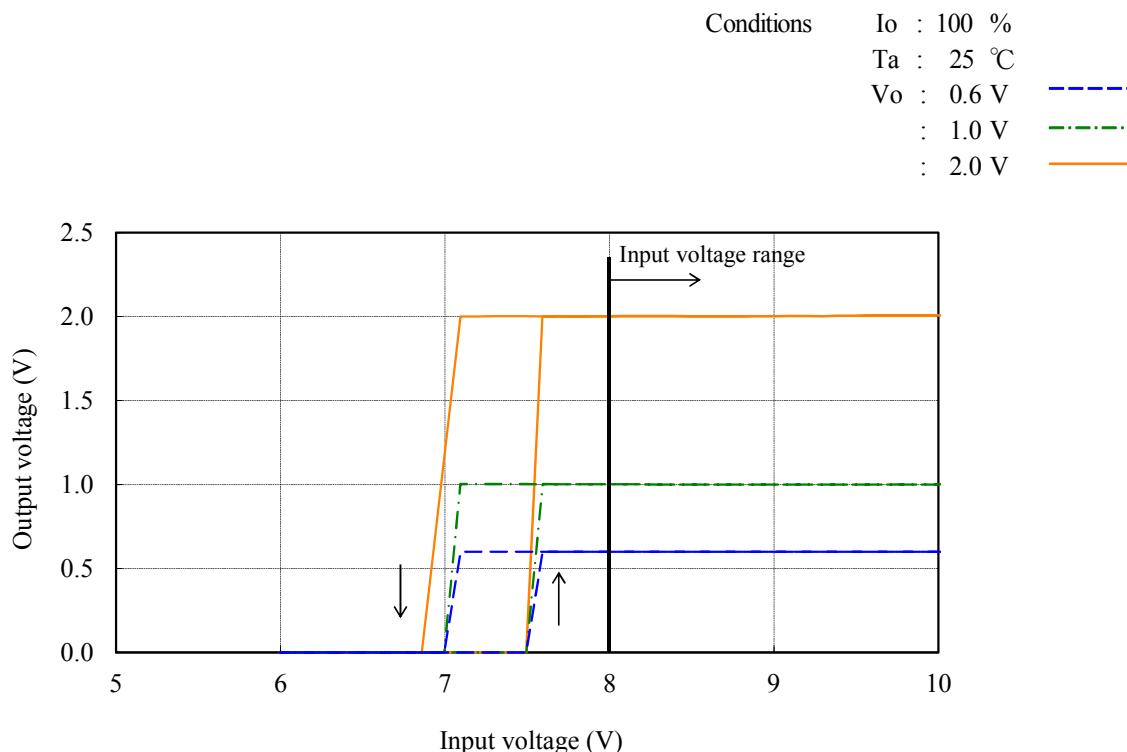


(5) 効率 対 温度 Efficiency vs. Temperature

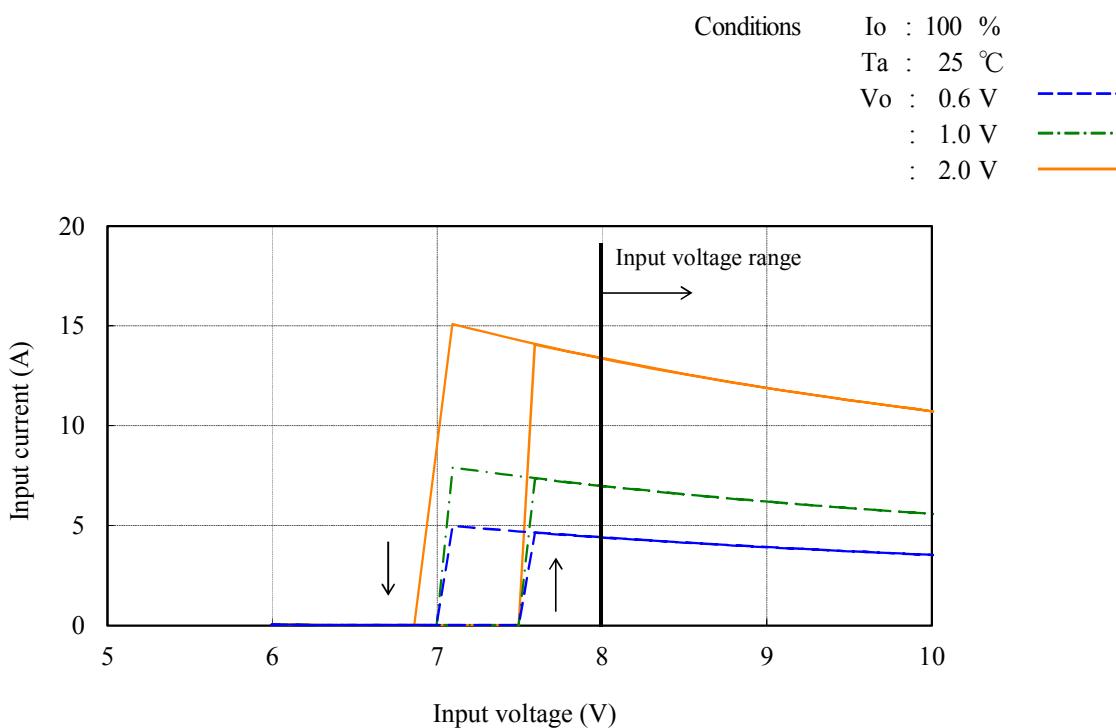


(6) 起動、停止電圧特性 Start and Stop voltage characteristics

出力電圧 対 入力電圧
Output voltage vs. Input voltage

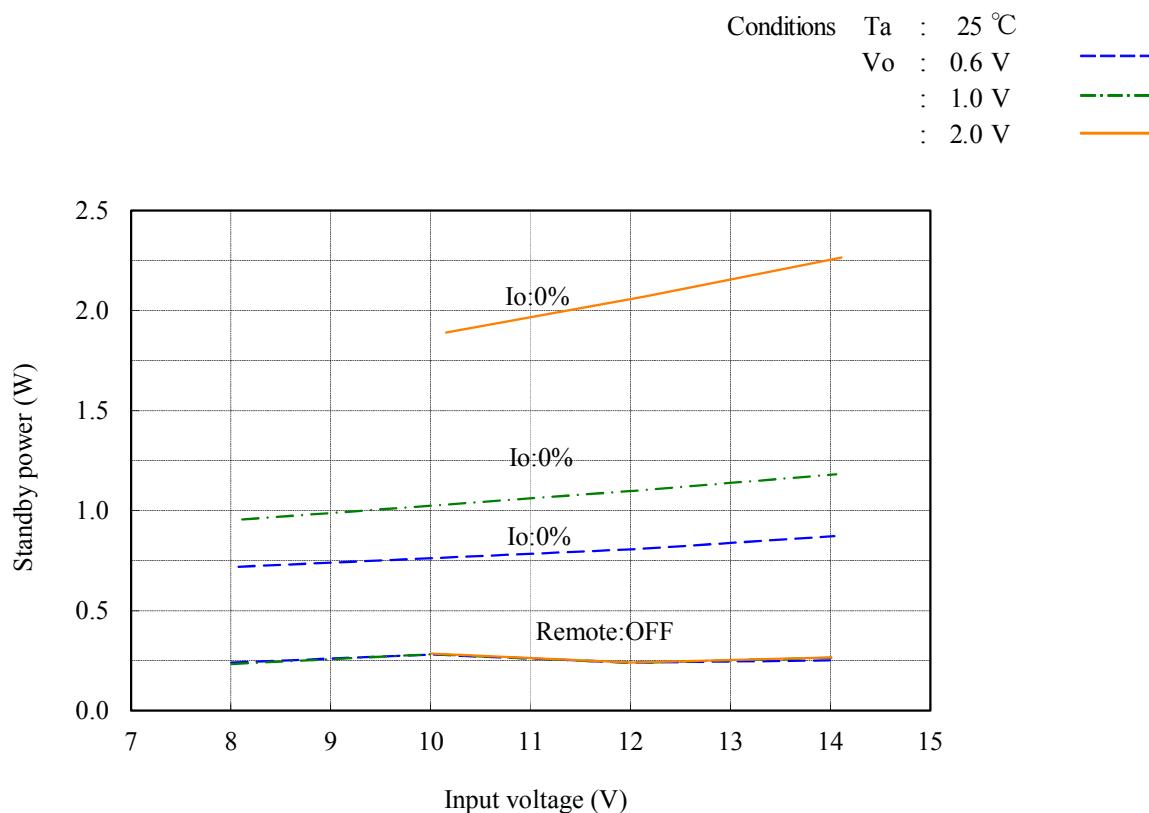


入力電流 対 入力電圧
Input current vs. Input voltage



2.2 待機電力特性

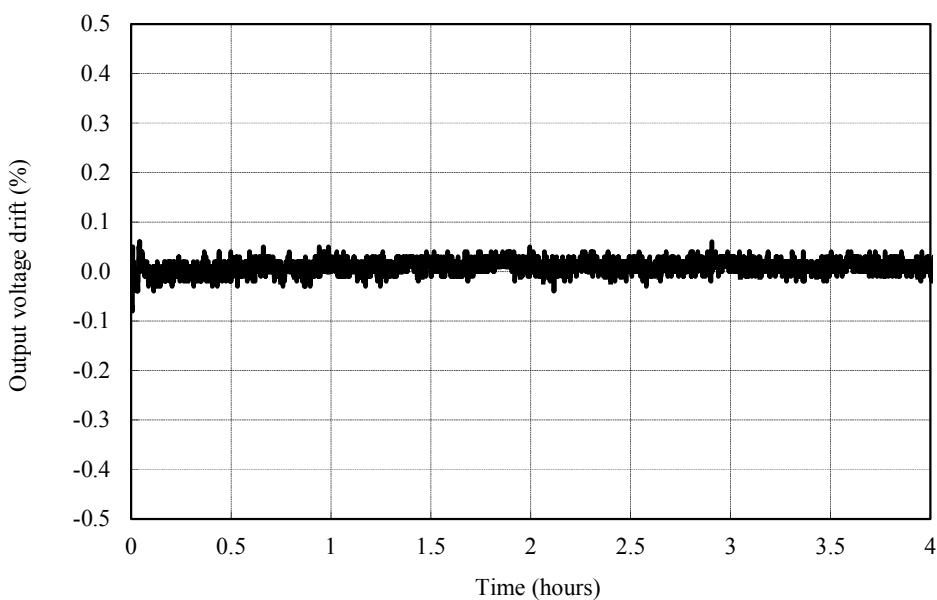
Standby power characteristics



2.3 通電ドリフト特性

Warm up voltage drift characteristics

Conditions Vin : 12 VDC
Vo : 1.0 V
Io : 100 %
Ta : 25 °C

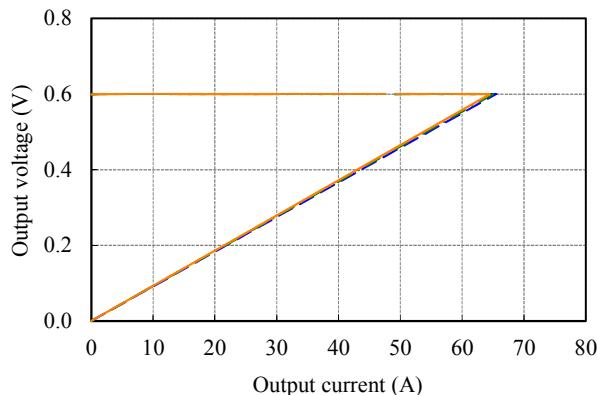


2.4 過電流保護特性 Over current protection (OCP) characteristics

入力電圧依存性

Input voltage dependence

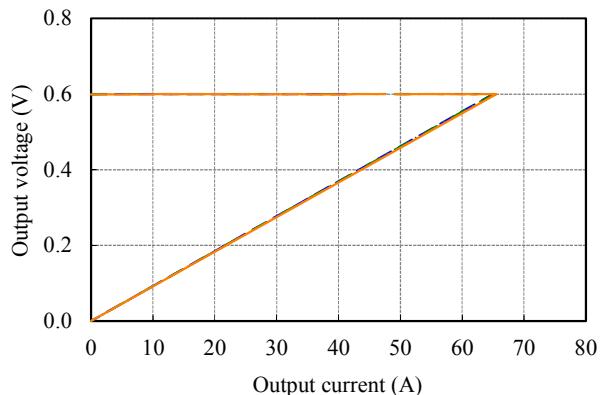
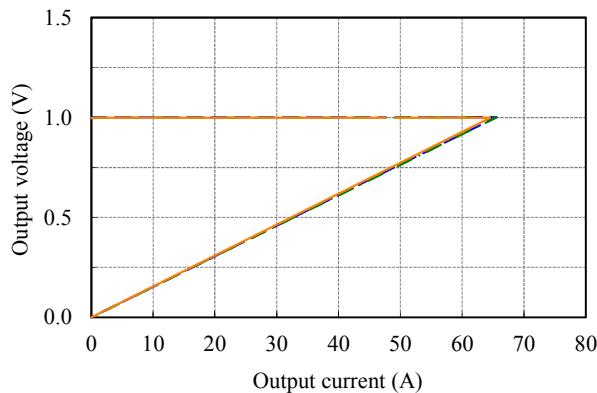
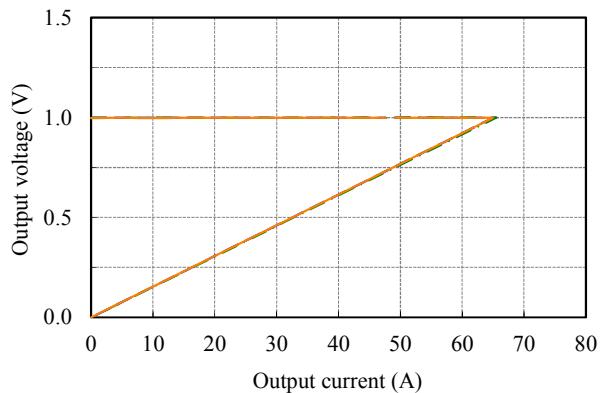
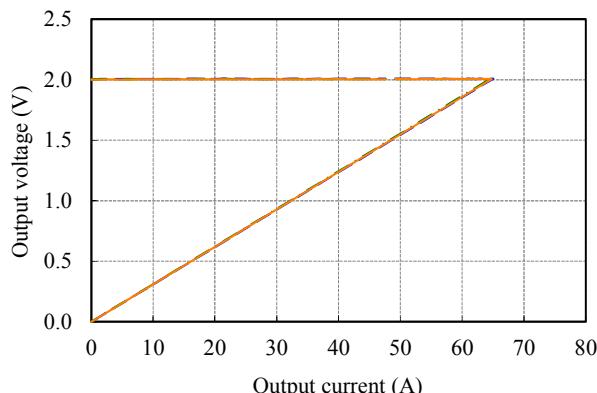
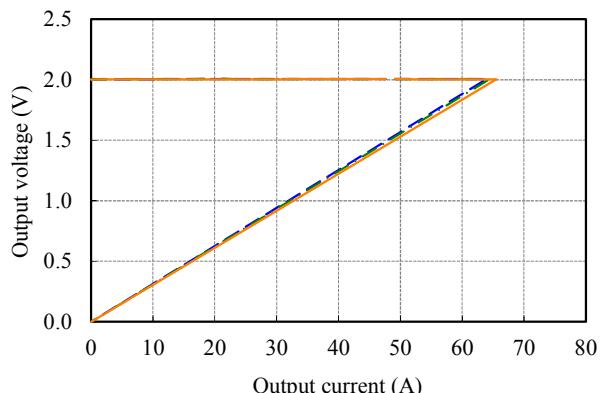
Conditions Vin : 8 VDC($V_o=0.6, 1.0V$)
 10 VDC($V_o=2.0V$)
 : 12 VDC
 : 14 VDC
 Ta : 25 °C

 $V_o = 0.6 \text{ V}$ 

周囲温度依存性

Ambient temperature dependence

Conditions Vin : 12 VDC
 Ta : -40 °C
 : 25 °C
 : 85 °C

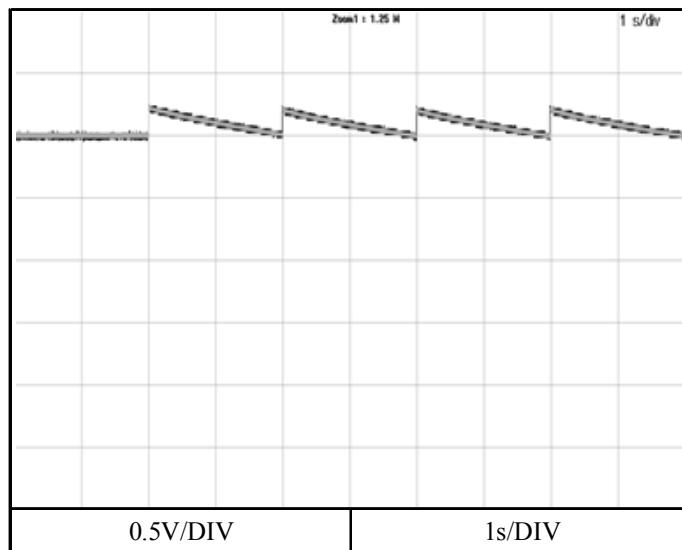
 $V_o = 0.6 \text{ V}$  $V_o = 1.0 \text{ V}$  $V_o = 1.0 \text{ V}$  $V_o = 2.0 \text{ V}$  $V_o = 2.0 \text{ V}$ 

2.5 過電壓保護特性 Over voltage protection (OVP) characteristics

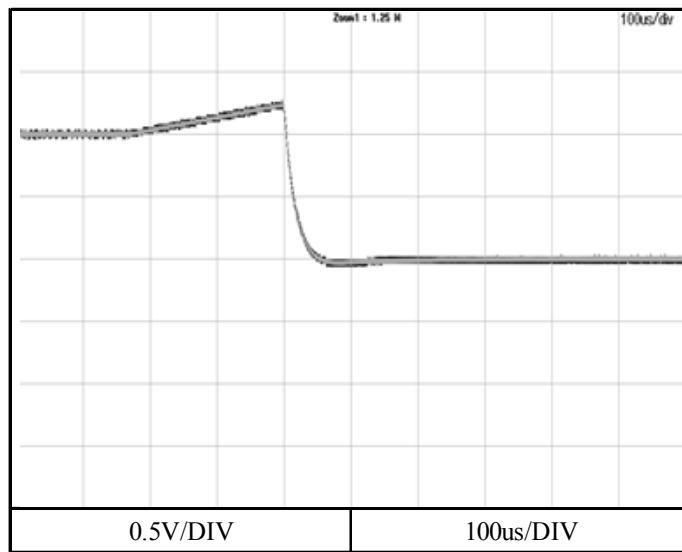
Conditions Vin : 12 VDC
 Vo : 1.0V
 Ta : 25 °C
OVP Setting : 1.2V

Io=0%OVP point →
Vo →

GND →

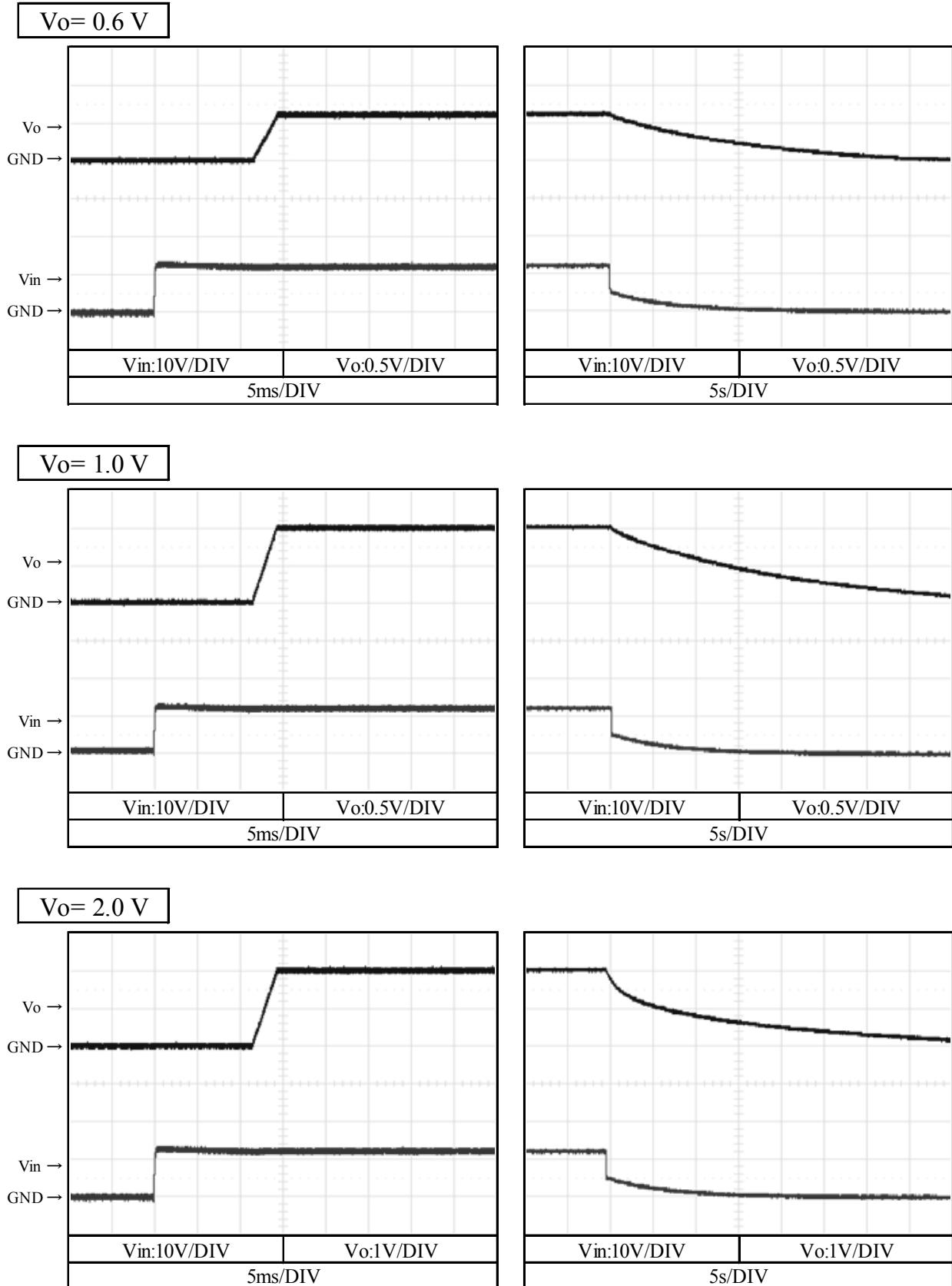
**Io=100%**OVP point →
Vo →

GND →



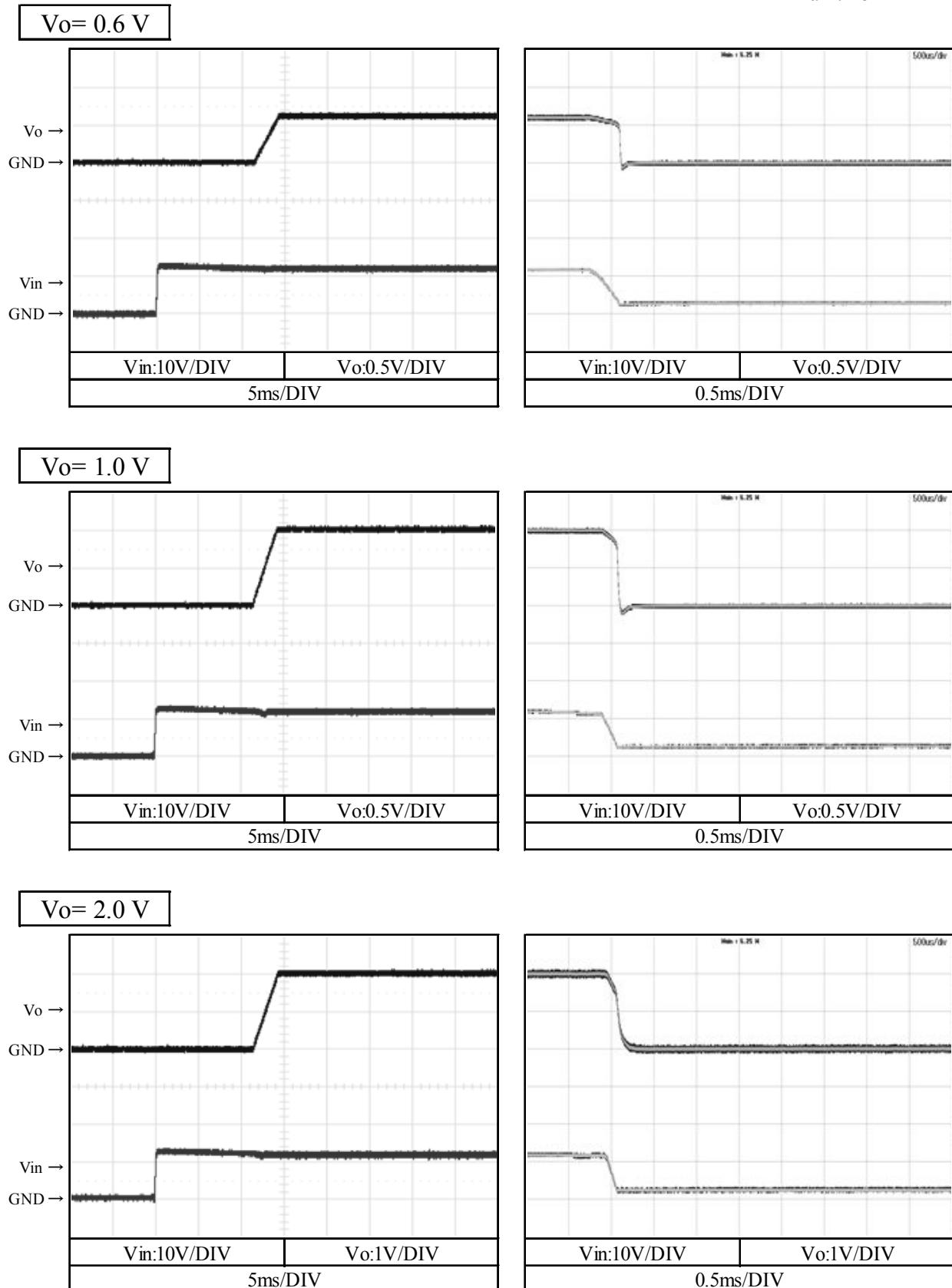
2.6 出力立ち上がり、立ち下がり特性 Output rise and fall characteristics

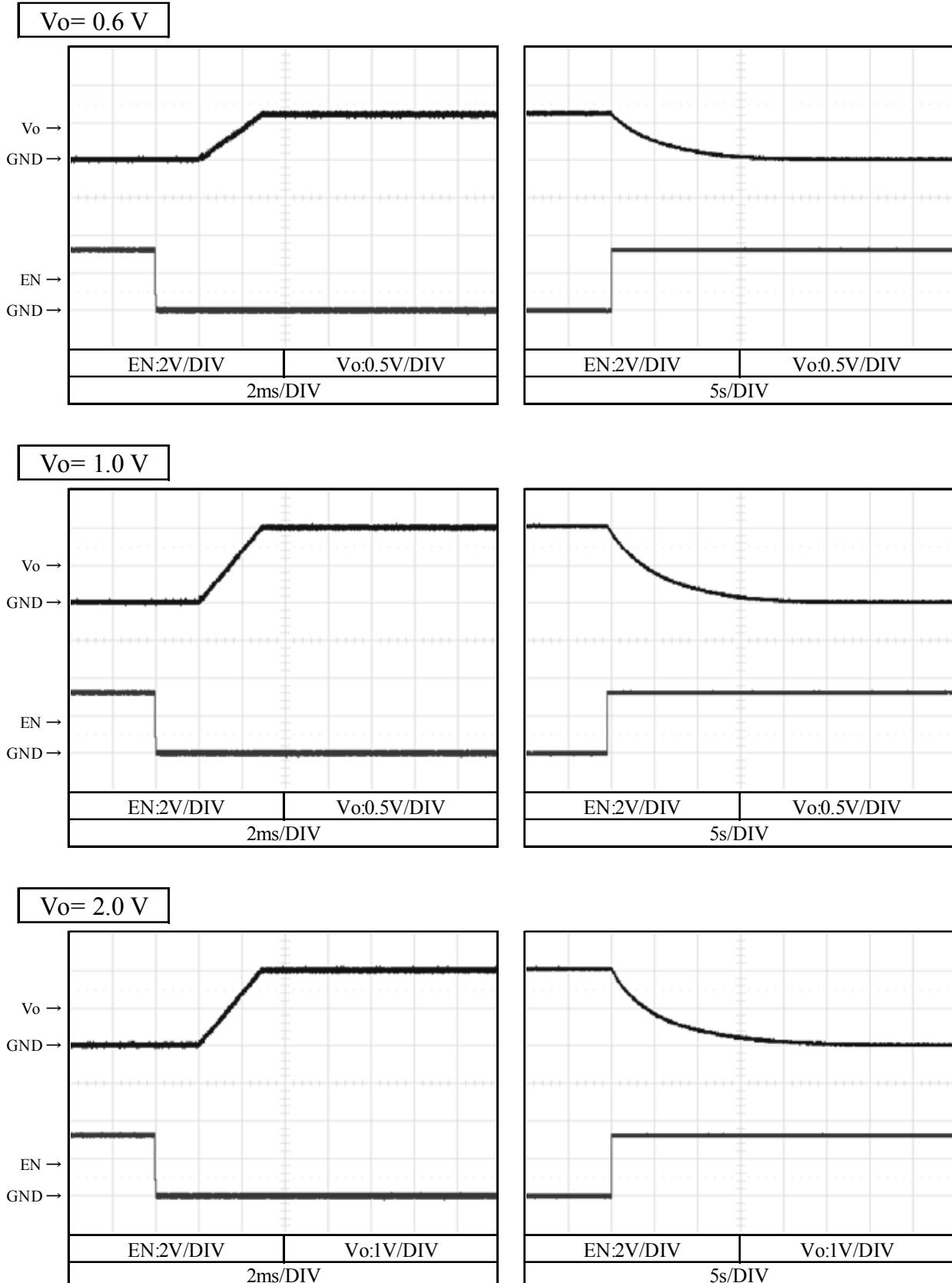
Conditions Vin : 12 VDC
 Io : 0 %
 Ta : 25 °C



2.6 出力立ち上がり、立ち下がり特性 Output rise and fall characteristics

Conditions Vin : 12 VDC
 Io : 100 %
 Ta : 25 °C

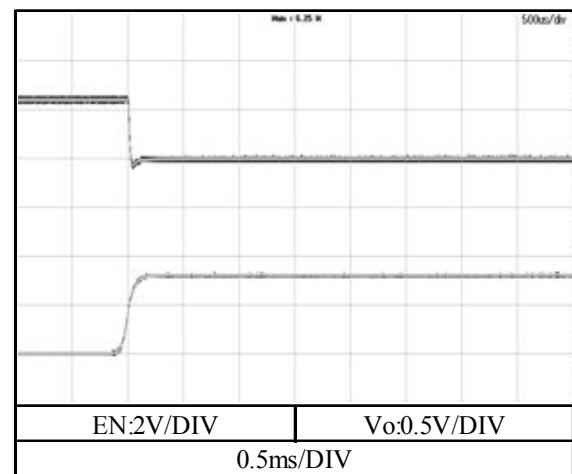
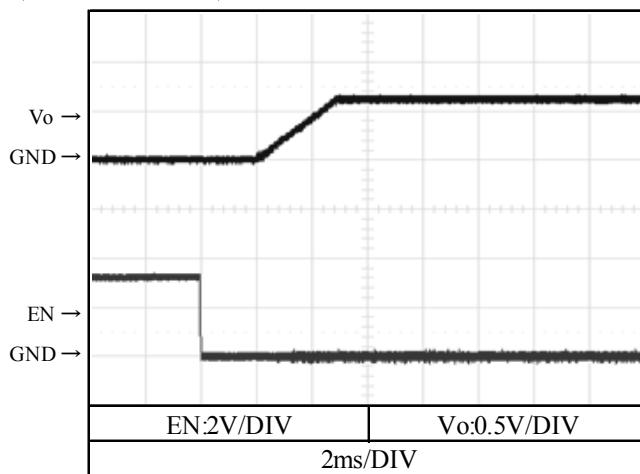


2.6 出力立ち上がり、立ち下がり特性 (リモートON/OFF時)
Output rise and fall characteristics with Remote ON/OFFConditions Vin : 12 VDC
 Io : 0 %
 Ta : 25 °C

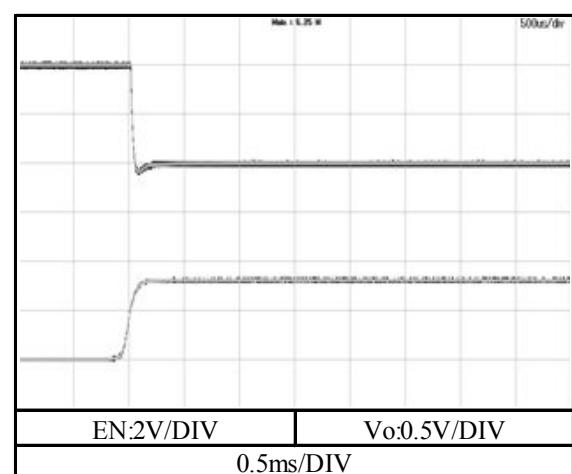
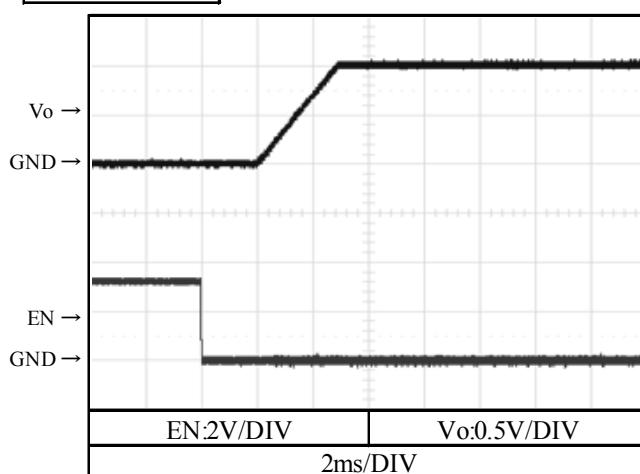
2.6 出力立ち上がり、立ち下がり特性 (リモートON/OFF時)
Output rise and fall characteristics with Remote ON/OFF

Conditions Vin : 12 VDC
 Io : 100 %
 Ta : 25 °C

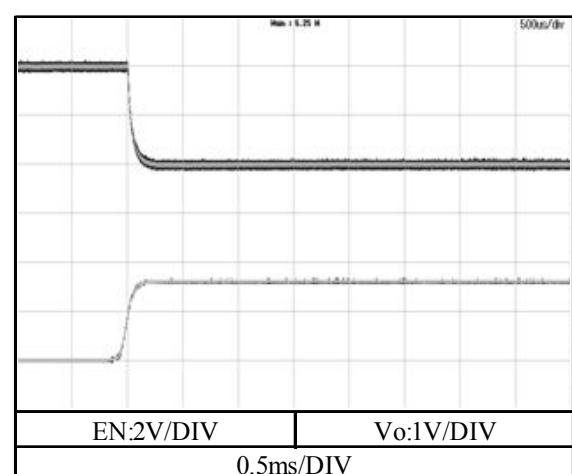
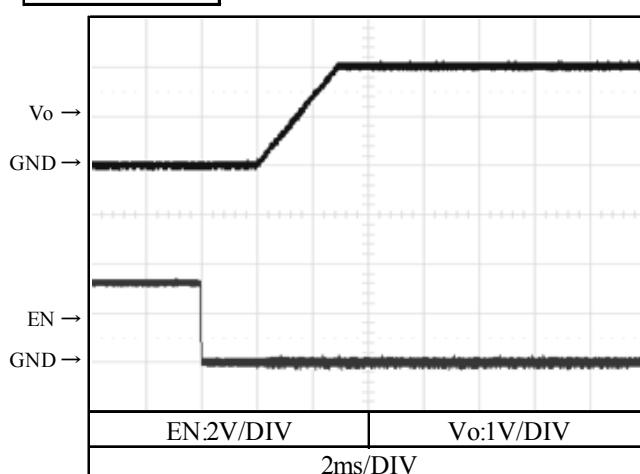
Vo= 0.6 V



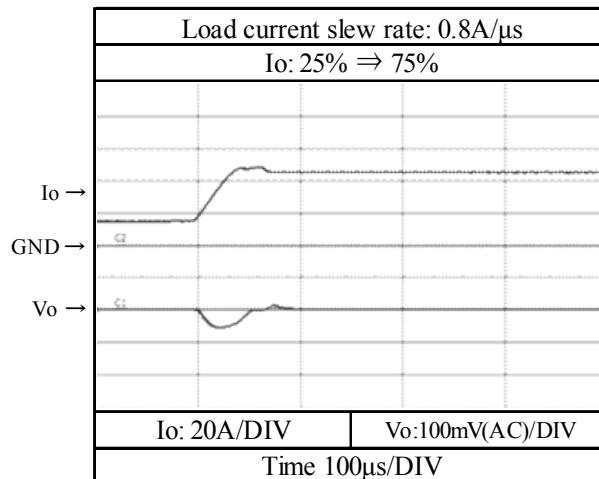
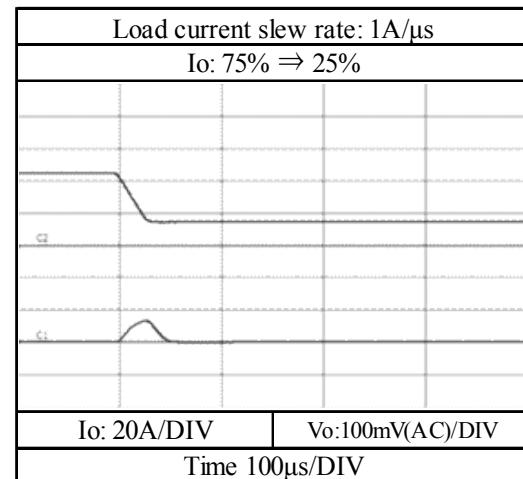
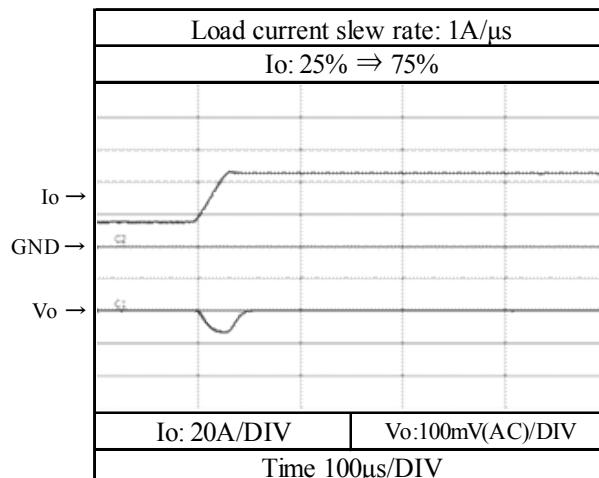
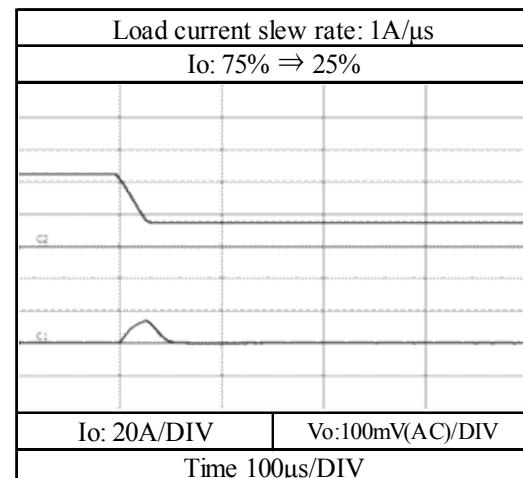
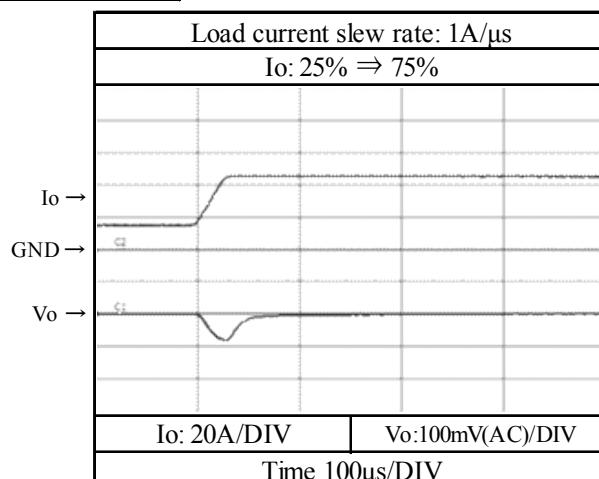
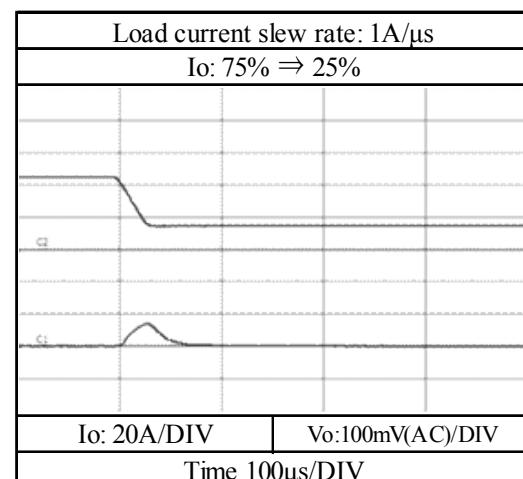
Vo= 1.0 V



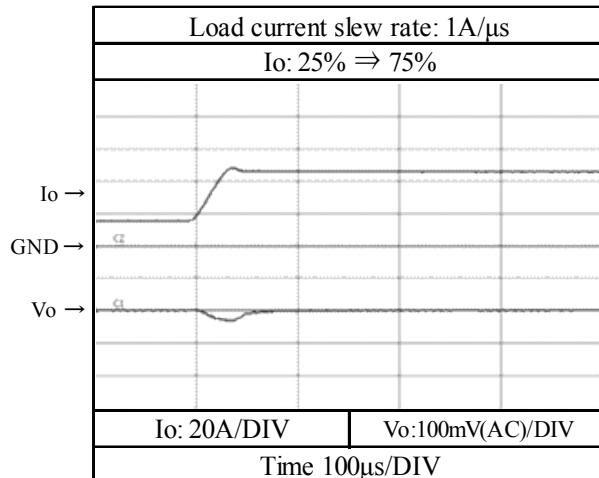
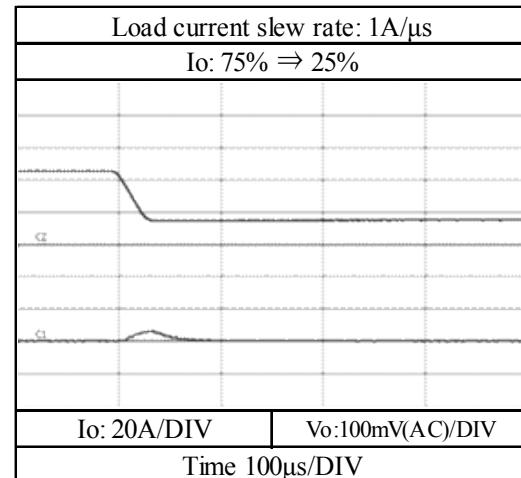
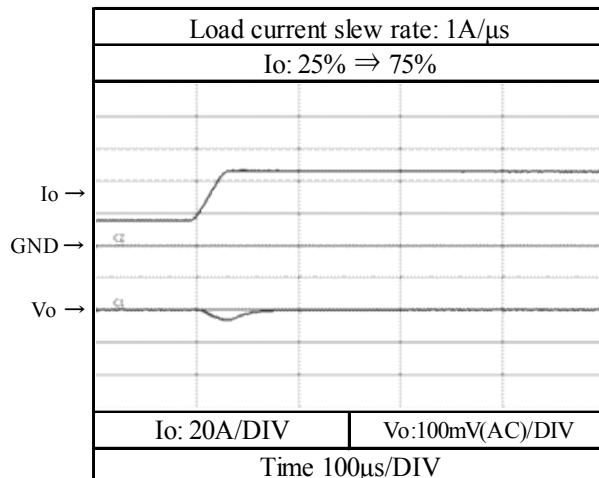
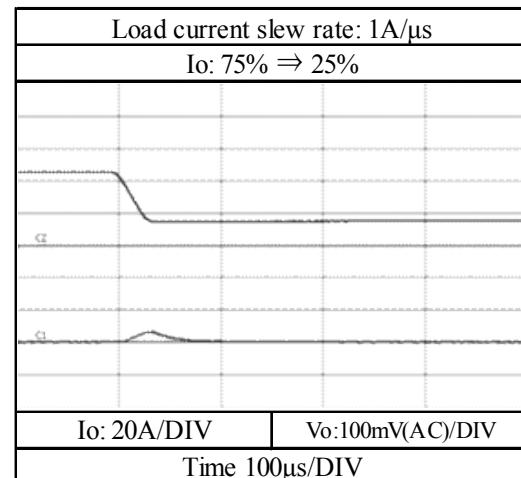
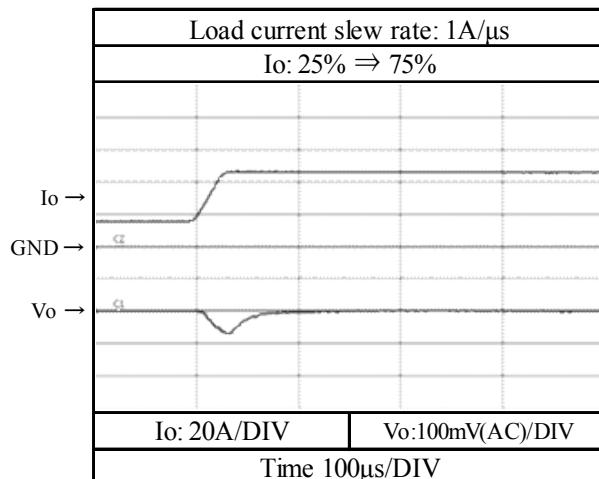
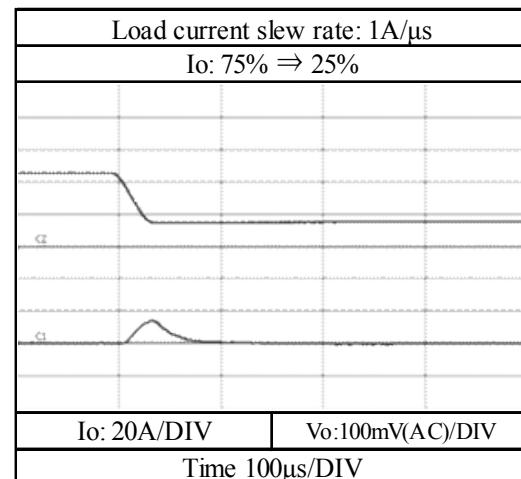
Vo= 2.0 V



2.7 過渡応答(負荷急変)特性 Dynamic load response characteristics

Transient Response : Standard OptionConditions Vin : 12 VDC
Ta : 25 °C**Vo=0.6V**Load current slew rate: 1A/μs
Io: 75% ⇒ 25%**Vo=1.0V**Load current slew rate: 1A/μs
Io: 75% ⇒ 25%**Vo=2.0V**Load current slew rate: 1A/μs
Io: 75% ⇒ 25%

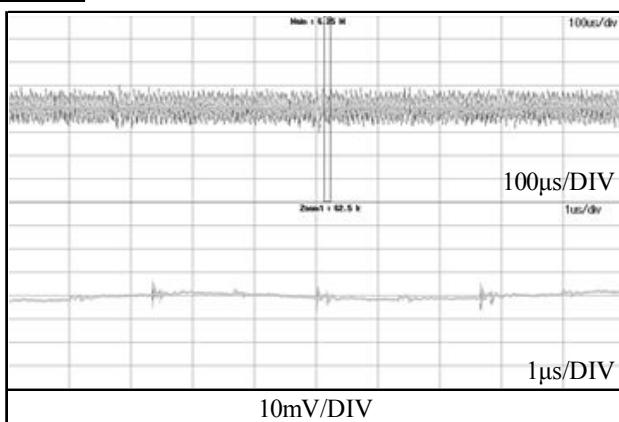
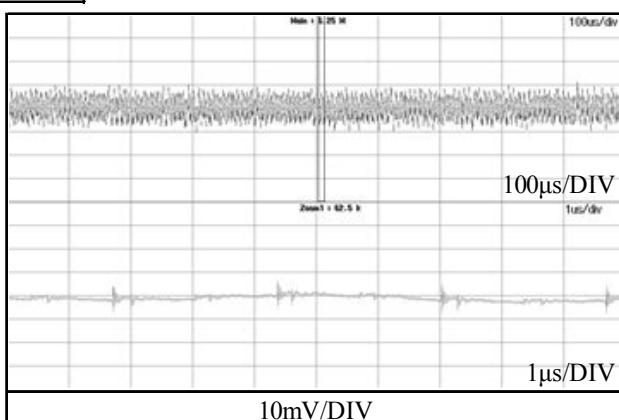
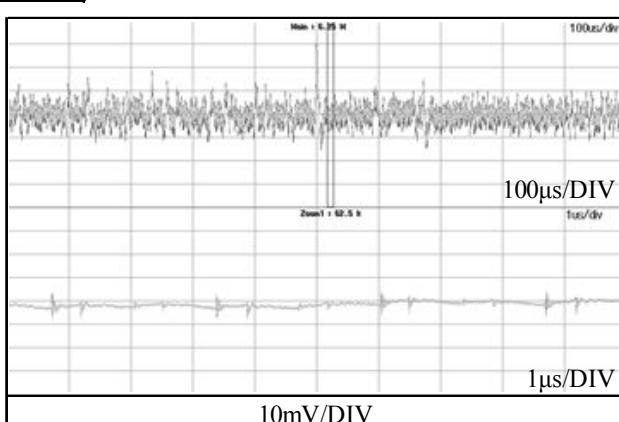
2.7 過渡応答(負荷急変)特性 Dynamic load response characteristics

Transient Response : Enhanced OptionConditions Vin : 12 VDC
Ta : 25 °C**Vo=0.6V**Load current slew rate: 1A/μs
Io: 75% ⇒ 25%**Vo=1.0V**Load current slew rate: 1A/μs
Io: 75% ⇒ 25%**Vo=2.0V**Load current slew rate: 1A/μs
Io: 75% ⇒ 25%

2.8 出力リップル、ノイズ波形 Output ripple and noise waveform

Transient Response : Standard Option

Conditions Vin : 12 VDC
 Io : 100 %
 Ta : 25 °C

Vo=0.6V**Vo=1.0V****Vo=2.0V**

2.8 出力リップル、ノイズ波形 Output ripple and noise waveform

Transient Response : Enhanced Option

Conditions Vin : 12 VDC
 Io : 100 %
 Ta : 25 °C

